

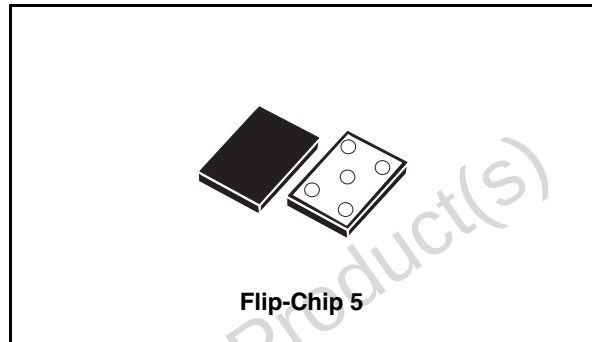


ST1G3234

1-bit dual supply bus buffer level translator with A-side series resistor

Features

- High speed: $t_{PD} = 4.4\text{ns}$ (Max.) at $T_A = 85^\circ\text{C}$
 $V_{CCB} = 1.65\text{V}$; $V_{CCA} = 3.0\text{V}$
- Low power dissipation:
 $I_{CCA} = I_{CCB} = 5\mu\text{A}$ (Max.) at $T_A = 85^\circ\text{C}$
- Symmetrical output impedance:
 $I_{OHA} = I_{OLA} = 10\text{mA}$ Min at
 $V_{CCA} = 2.75\text{V}$; $V_{CCB} = 1.4\text{V}$ to 3.6V
 $I_{OHA} = I_{OLA} = 6\text{mA}$ Min at
 $V_{CCA} = 2.3\text{V}$; $V_{CCB} = 1.4\text{V}$ to 3.6V
- Balanced propagation delays:
 $t_{PLH} \equiv t_{PHL}$
- Power down protection on inputs and outputs
- 26Ω series resistor on A-side outputs
 - Operating voltage range:
 $V_{CCA}(\text{Opr}) = 1.4\text{V}$ to 3.6V (1.2V data retent)
 $V_{CCB}(\text{Opr}) = 1.4\text{V}$ to 3.6V (1.2V data retent)
- Max data rates:
380Mbps (1.8V to 3.3V translation)
260Mbps (<1.8V to 3.3V translation)
260Mbps (translate to 2.5V)
210Mbps (translate to 1.5V)
- Latch-up performance exceeds 500mA (JESD 17)
- ESD performance:
HBM > 2000V (MIL STD 883 method 3015);
MM > 200V
- RoHS compliant for Flip-Chip package



Description

The ST1G3234 is a dual supply low voltage CMOS 1-Bit bus buffer level translator fabricated with sub-micron silicon gate and five-layer metal wiring C²MOS technology. Designed for use as an interface between a 3.3V bus and a 2.5V or 1.8V bus in a mixed 3.3V/1.8V, 3.3V/2.5V, 1.8V/1.4V and 2.5V/1.8V supply systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

This IC is intended for one-way asynchronous communication between data buses. The input and output power down protections disable the device when both power supply are down, so that the buses are effectively isolated.

The input tolerant buffers allow to translate V_{CCB} compatible signals and greater signals than V_{CCB} up/down to V_{CCA} .

All inputs are equipped with protection circuits against static discharge, giving them ESD immunity and transient excess voltage.

Order codes

Part number	Package	Comments
ST1G3234BJR	Flip-Chip 5	4000 parts per reel

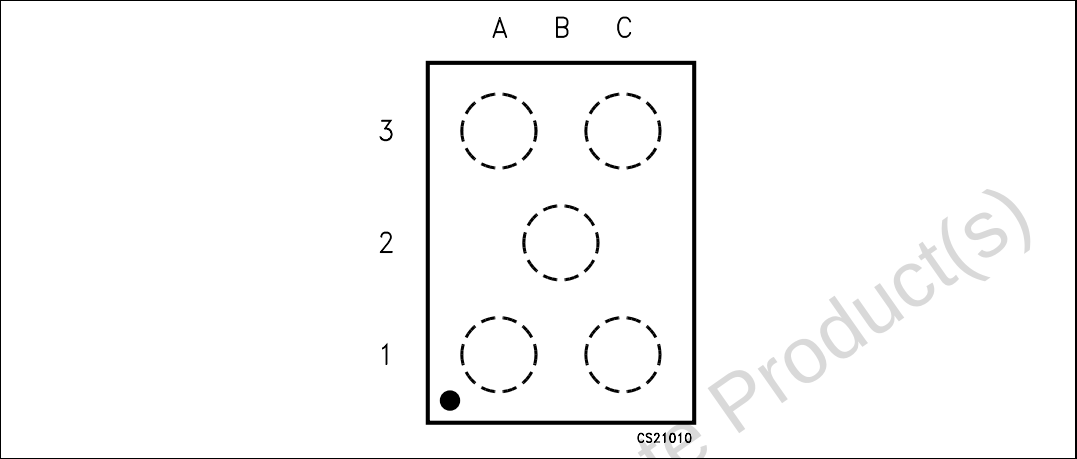
Contents

1	Pin settings	3
1.1	Pin connection	3
1.2	Pin description	3
2	Device summary	4
3	Maximum rating	5
3.1	Recommended operating conditions	6
4	Electrical characteristics	7
5	Test circuit	9
6	Waveforms	10
7	Package mechanical data	11
8	Revision history	14

1 Pin settings

1.1 Pin connection

Figure 1. Pin connection (top through view)



1.2 Pin description

Table 1. Pin description

Pin N°	Symbol	Name and function
A1	A1	Data output (V_{CCA} referred)
C1	B1	Data input (V_{CCB} referred)
B2	GND	Ground (0V)
A3	V_{CCA}	Positive supply voltage
C3	V_{CCB}	Positive supply voltage

2 Device summary

Figure 2. Input equivalent circuit

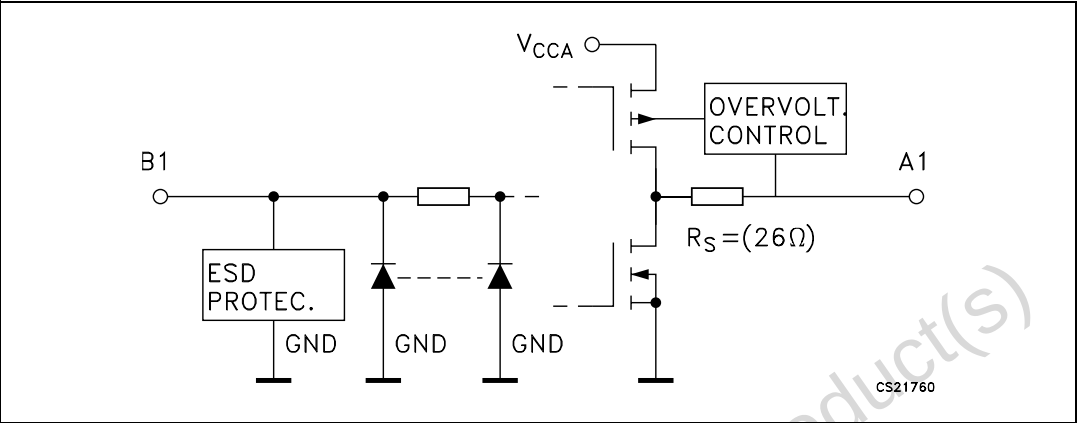


Figure 3. Logic diagram

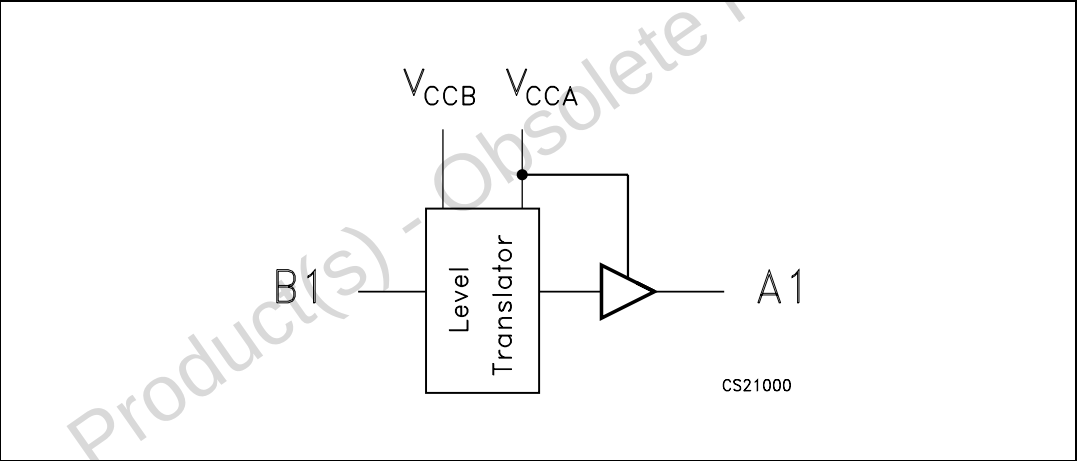


Table 2. Truth table

Inputs B1 (V_{CCB} Referred)	Outputs A1 (V_{CCA} Referred)
L	L
H	H

3 Maximum rating

Stressing the device above the rating listed in the “Absolute Maximum Ratings” table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CCA}	Output supply voltage	-0.5 to +4.6	V
V_{CCB}	Input supply voltage	-0.5 to + 4.6	V
V_{OA}	DC output voltage (power down mode: $V_{CCA}=V_{CCB}=Gnd$)	-0.5 to +4.6	V
V_{IB}	DC input voltage (power down mode: $V_{CCA}=V_{CCB}=Gnd$)	-0.5 to +4.6	V
V_{OA}	DC output voltage	-0.5 to $V_{CCA} + 0.5$	V
V_{IB}	DC input voltage	-0.5 to + 4.6	V
I_{IK}	DC input diode current	-20	mA
I_{OK}	DC output diode current	-50	mA
I_{OA}	DC output current	±50	mA
I_{CCA}	DC V_{CCA} or ground current	±100	mA
I_{CCB}	DC V_{CCB} or ground current	±100	mA
P_d	Power dissipation	200	mW
T_{stg}	Storage temperature	-65 to +150	°C
T_L	Lead temperature (10 sec)	260	°C

3.1 Recommended operating conditions

Table 4. Recommended operating conditions

Symbol	Parameter		Value	Unit
V_{CCA}	Supply voltage		1.4 to 3.6	V
V_{CCB}	Supply voltage		1.4 to 3.6	V
V_{IB}	Input voltage (B1)		0 to V_{CCB}	V
V_{OA}	Output voltage (A1)		0 to V_{CCA}	V
T_{op}	Operating temperature		-40 to 85	°C
dt/dv	Input Rise and Fall Time ⁽¹⁾	$V_{CCB} = 3.0$ to $3.6V$	0 to 10	ns/V
		$V_{CCB} = 2.3$ to $2.7V$	0 to 20	ns/V
		$V_{CCB} = 1.4$ to $1.95V$	0 to 100	ns/V

1. VI from 0.8V to 2.0V at $V_{CC} = 3.0V$

4 Electrical characteristics

Table 5. DC specification

Symbol	Parameter	Test condition			Value				Unit
		V _{CCB} (V) ⁽¹⁾	V _{CCA} (V) ⁽¹⁾		T _A = 25 °C		-40 to 85 °C		
					Min	Max	Min	Max	
V _{IHB}	High level input voltage	1.4	1.4 to 3.6V		0.65V _{CCB}		0.65V _{CCB}		V
		1.8			0.65V _{CCB}		0.65V _{CCB}		
		2.5			1.6		1.6		
		3.3			2.0		2.0		
V _{ILB}	Low level input voltage	1.4	1.4 to 3.6V			0.35V _{CCB}		0.35V _{CCB}	V
		1.8				0.35V _{CCB}		0.35V _{CCB}	
		2.5				0.7		0.7	
		3.3				0.8		0.8	
V _{OHA}	High level output voltage	1.4 to 3.6V	1.4	I _O =-100μA	1.2		1.2		V
			2.75	I _O =-10mA	2.2		2.2		
			2.3	I _O =-6mA	1.8		1.8		
			1.65	I _O =-2mA	1.4		1.4		
			1.4	I _O =-1mA	1.1		1.1		
V _{OLA}	Low level output voltage	1.4 to 3.6V	1.4	I _O =100μA		0.20		0.20	V
			2.75	I _O =1mA		0.40		0.40	
			2.75	I _O =10mA		0.55		0.55	
			2.3	I _O =6mA		0.40		0.40	
			1.65	I _O =2mA		0.25		0.25	
			1.4	I _O =1mA		0.20		0.20	
I _{IB}	Input leakage current	2.7	3.6	V _{IB} =V _{CCB} or GND		±0.5		±5	μA
		1.4	2.7	V _{IB} =3.6V or GND		±0.5		±5	μA
I _{OFF}	Power OFF leakage current	0	0	V _{IB} =GND to 3.6V V _{OA} =GND to 3.6V		±1.0		±10	μA
I _{CC1B}	Quiescent supply current	1.4 to 3.6V	1.4 to 3.6V	V _{IB} =V _{CCB} or GND		0.5		5	μA
I _{CC1A}	Quiescent supply current	1.4 to 3.6V	1.4 to 3.6V	V _{IB} =V _{CCB} or GND		0.5		5	μA

1. V_{CC} range = 3.3 ± 0.3 ; $2.5 \pm 0.2\text{V}$; $1.8 \pm 0.15\text{V}$

Table 6. AC electrical characteristics

Symbol	Parameter	Test condition			Value		Unit
		V _{CCB} (V)	V _{CCA} (V)		-40 to 85 °C		
					Min	Max	
t _{PLH} t _{PHL}	Propagation delay time B1 to A1	2.3 to 3.6	1.4	C _L = 10 pF	2.0	5.0	ns
		1.4 to 1.95	1.4		2.0	5.0	
		2.3 to 3.6	1.65 to 1.95		2.0	4.5	
		1.4 to 1.95	1.65 to 1.95		2.0	4.8	
		1.4 to 1.95	2.3 to 2.7		2.0	3.5	
		1.4 to 1.95	3.0 to 3.6		2.0	3.5	
		2.3 to 2.7	3.0 to 3.6		1.0	3.0	
t _{PLH} t _{PHL}	Propagation delay time B1 to A1	2.3 to 3.6	1.4	C _L = 30 pF R _L = 500 Ω	2.0	5.5	ns
		1.4 to 1.95	1.4		2.0	5.5	
		2.3 to 3.6	1.65 to 1.95		2.0	5.0	
		1.4 to 1.95	1.65 to 1.95		2.0	5.2	
		1.4 to 1.95	2.3 to 2.7		2.0	4.0	
		1.4 to 1.95	3.0 to 3.6		2.0	4.0	
		2.3 to 2.7	3.0 to 3.6		1.0	3.5	

Table 7. Capacitance characteristics

Symbol	Parameter	Test condition			Value					Unit
		V _{CCB} (V)	V _{CCA} (V)		T _A = 25 °C			-40 to 85 °C		
					Min	Typ	Max	Min	Max	
C _{INB}	Input capacitance	open	open			5				pF
C _O	Output capacitance	2.5	3.3			6				pF
C _{PD}	Power dissipation capacitance	2.5	3.3	f = 10MHz		27				pF
		1.8	3.3			27				
		1.4	2.5			23				
		1.4	1.8			20				
		3.3	1.8			27				

Note: 1 C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$ (per circuit)

5 Test circuit

Figure 4. Test circuit

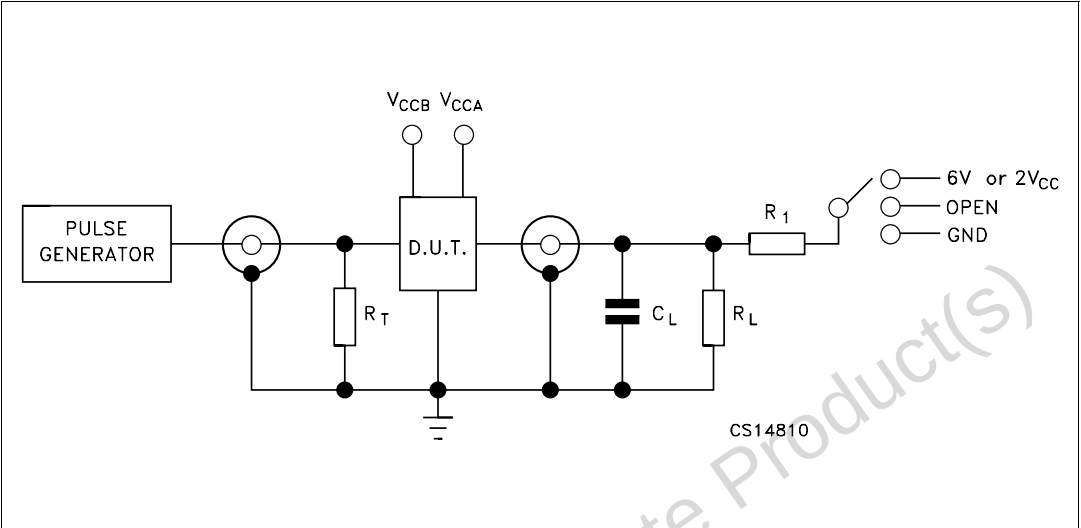


Table 8. Test circuit

Test	Switch
t_{PLH} , t_{PHL}	Open

$C_L = 10/30\text{pF}$ or equivalent (includes jig and probe capacitance)

$R_L = R_1 = 500\Omega$ or equivalent

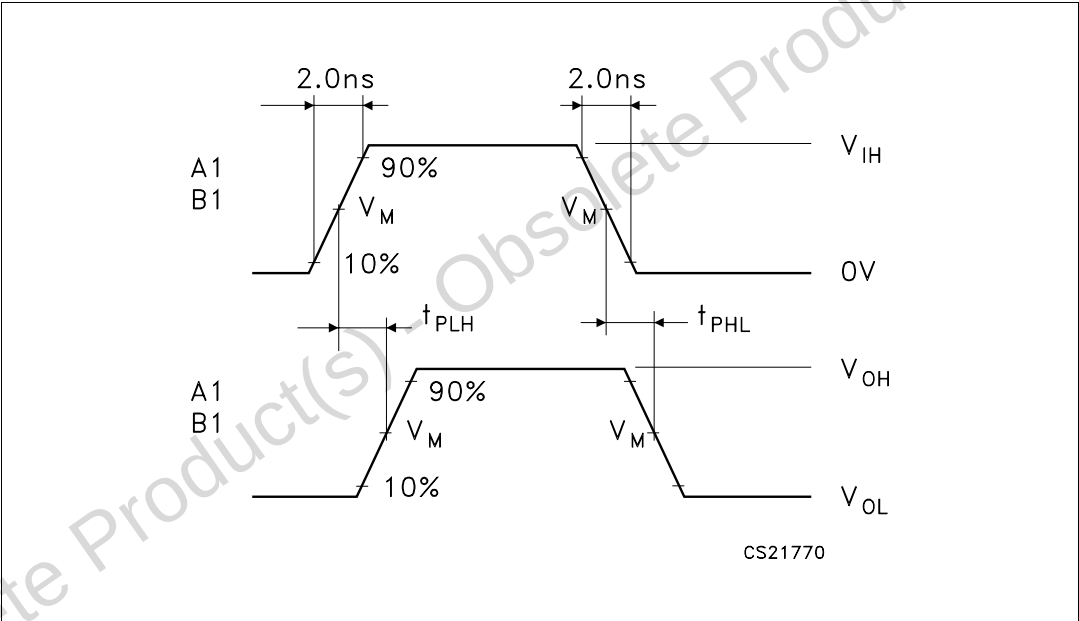
$R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

6 Waveforms

Table 9. Waveform symbol value

Symbol	V_{CC}		
	3.0 to 3.6V	2.3 to 2.7V	1.65 to 1.95V
V_{IH}	V_{CC}	V_{CC}	V_{CC}
V_M	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_X	$V_{OL} + 0.3V$	$V_{OL} + 0.15V$	$V_{OL} + 0.15V$
V_Y	$V_{OL} - 0.3V$	$V_{OL} - 0.15V$	$V_{OL} - 0.15V$

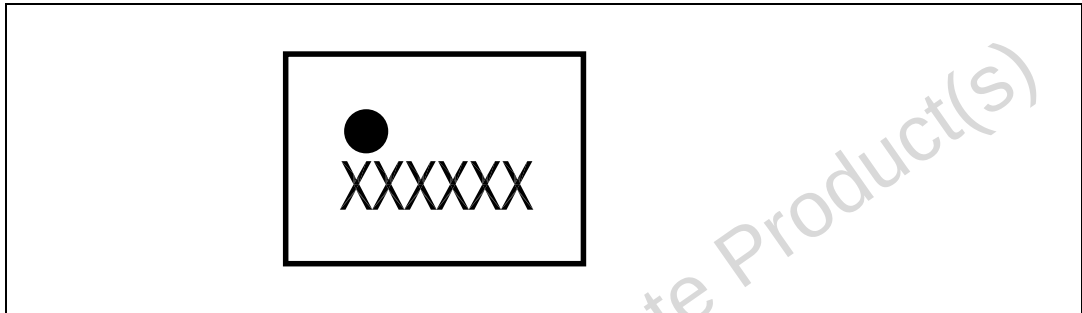
Figure 5. Waveform - propagation delay (f = 1MHz; 50% duty cycle)



7 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

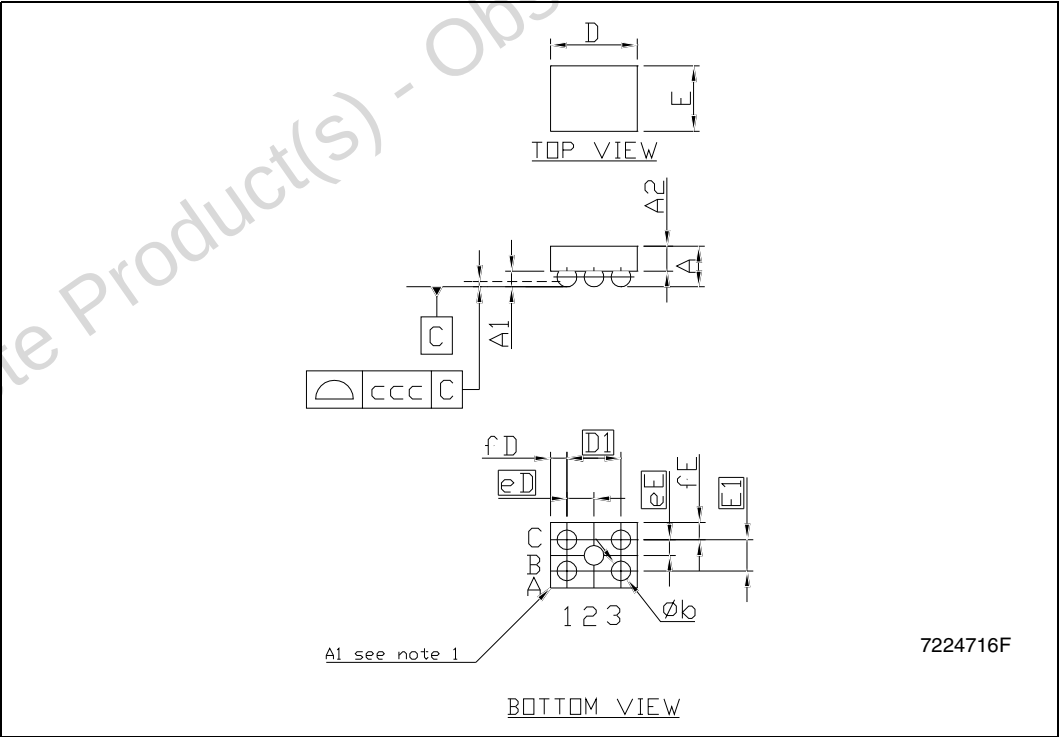
Figure 6. Marking



Note: X = Marking Area; Marking Code 9537

Flip-Chip 5 MECHANICAL DATA	
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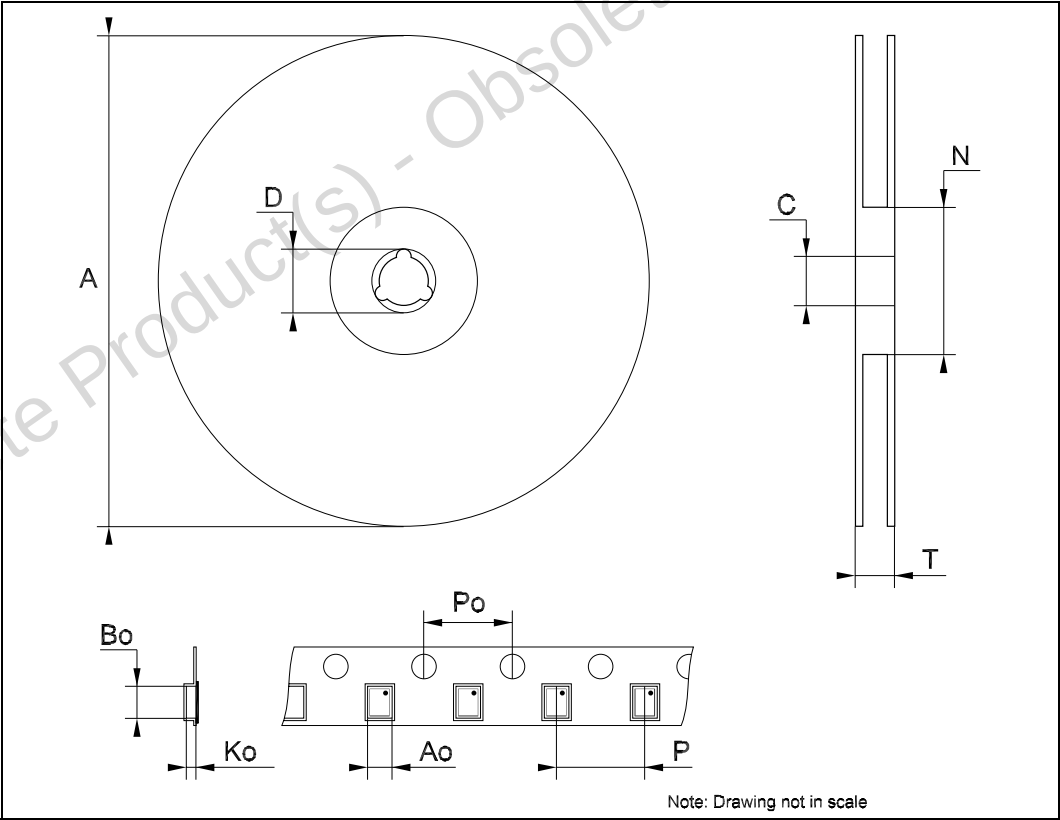
DIM.	mm.			mils		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	0.585	0.65	0.715	23.0	25.6	28.1
A1	0.21	0.25	0.29	8.3	9.8	11.4
a2		0.40			15.7	
b	0.265	0.315	0.365	10.4	12.4	14.4
D	1.31	1.36	1.41	51.6	53.5	55.5
D1		0.866			34.1	
E	0.97	1.02	1.07	38.2	40.2	42.1
E1		0.5			19.7	
eD	0.383	0.433	0.483	15.1	17.0	19.0
eE	0.20	0.25	0.30	7.9	9.8	11.8
fD		0.247			9.7	
fE		0.260			10.2	
ccc		0.080			3.1	



7224716F

Tape & Reel Flip-Chip 5 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			178			6.926
C	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	49	50	51	1.929	1.969	2.008
T			12.4			0.488
Ao	1.60	1.65	1.70	0.063	0.065	0.067
Bo	1.27	1.32	1.37	0.050	0.052	0.054
Ko	0.76	0.81	0.86	0.030	0.032	0.034
Po	3.9	4	4.1	0.153	0.157	0.161
P	3.9	4	4.1	0.153	0.157	0.161



8 Revision history

Table 10. Revision history

Date	Revision	Changes
14-Oct-2004	1	First release.
20-Dec-2004	2	Revision on Table 3 .
11-Feb-2005	3	Add Tape & Reel, Figures 2, 3, 5, 6, Table 3 , 5 , 7 and Mechanical Data has been modified.
30-Mar-2005	4	Add features ==> Max data rates.
09-May-2005	5	Table 7 and Table 8 have been updated.
16-Aug-2006	6	New template, updated test condition V_{OHA} Table 5

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